

## PC956L0NSZ0F Series

# High Speed 2Mb/s, High CMR DIP 8 pin \*OPIC Photocoupler



#### ■ Description

**PC956L0NSZ0F Series** contains a LED optically coupled to an OPIC chip.

It is packaged in a 8 pin DIP, available in SMT gullwing lead form option.

Input-output isolation voltage(rms) is 5.0kV, High speed response (TYP. 2Mb/s) and CMR is MIN.  $15kV/\mu s$ .

#### **■** Features

- 1. 8 pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- High noise immunity due to high instantaneous common mode rejection voltage (CM<sub>H</sub>: MIN. 15kV/μs, CM<sub>L</sub>: MIN. –15kV/μs)
- 4. High speed response

(t<sub>PHL</sub>: TYP. 210 ns, t<sub>PLH</sub>: TYP. 400 ns)

- 5. High isolation voltage between input and output (V<sub>iso(rms)</sub>: 5.0 kV)
- 6. Lead-free and RoHS directive compliant

#### ■ Agency approvals/Compliance

- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC956L)
- 2. Approved by VDE, DIN EN60747-5-2<sup>(\*)</sup> (as an option), file No. 40008898 (as model No. **PC956L**)
- 3. Package resin: UL flammability grade (94V-0)

#### ■ Applications

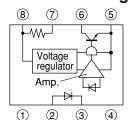
- 1. Programmable controller
- 2. Inverter

<sup>(\*)</sup> DIN EN60747-5-2: successor standard of DIN VDE0884

<sup>\* &</sup>quot;OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.



#### ■ Internal Connection Diagram

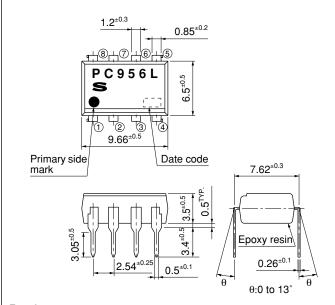


- ① NC
- ⑤ GND
- 2 Anode3 Cathode
- 4 NC

#### **■** Outline Dimensions

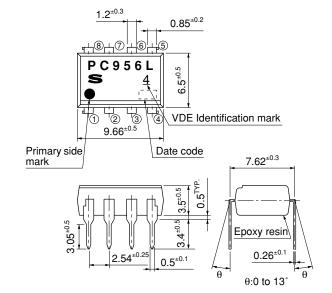
(Unit: mm)

1. Through-Hole [ex. PC956L0NSZ0F]



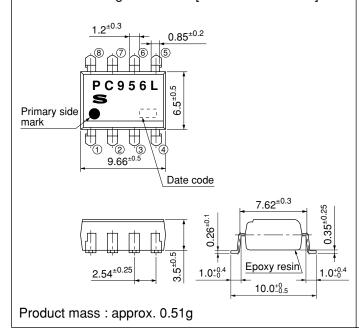
Product mass: approx. 0.55g

2. Through-Hole (VDE option) [ex. **PC956L0YSZ0F**]

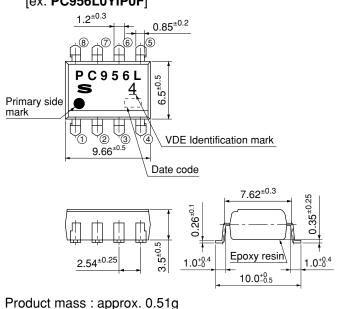


Product mass: approx. 0.55g

3. SMT Gullwing Lead-Form [ex. PC956L0NIP0F]



SMT Gullwing Lead-Form (VDE option) [ex. PC956L0YIP0F]



Plating material: SnCu (Cu: TYP. 2%)



## Date code (2 digit)

1st digit				2nd digit		
Year of production				Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin Japan

## Rank mark

There is no rank mark indicator.



■ Absolute Maximum Ratings

 $(T_a=25^{\circ}C)$ 

				-a -c -c)
Parameter		Symbol	Rating	Unit
	*1 Forward current	$I_F$	25	mA
Input	Reverse voltage	$V_R$	5	V
	*2 Power dissipation	P	45	mW
	Supply voltage	V <sub>CC</sub>	-0.5 to +35	V
Output	Output voltage	Vo	-0.5 to +35	V
	Output current	$I_{O}$	15	mA
	*3 Power dissipation	Po	100	mW
Operating temperature		Topr	-40 to +85	°C
Storage temperature		$T_{stg}$	-55 to +125	°C
*4 Isolation voltage		V <sub>iso (rms)</sub>	5.0	kV
*5 Soldering temperature		$T_{sol}$	270	°C

<sup>\*1</sup> When ambient temperature goes above 70°C, the power dissipation goes down at approx. 0.5mA/°C.(Fig.3)

## ■ Electro-optical Characteristics\*6

(unless otherwise specified  $T_a=-40$  to  $+85^{\circ}$ C,  $V_{CC}=4.5$  to 35V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		$T_a=25$ °C, $I_F=10$ mA	-	1.6	1.95	V
Input	Reverse current	$I_R$	$T_a=25^{\circ}C, V_R=5V$	-	_	10	μΑ
Τ	Terminal capacitance	Ct	T <sub>a</sub> =25°C, V=0, f=1MHz	_	60	250	pF
	Operating supply voltage	$V_{CC}$	-	4.5	_	35	V
	Low level output voltage	V <sub>OL</sub>	$I_F=10mA, I_o=2.4mA$	-	0.3	0.6	V
Output	Low level output current	$I_{OL}$	$I_{F}=10\text{mA}, V_{o}=0.6\text{V}$	4.4	9	_	mA
Out	High level output current	I <sub>OH</sub>	$I_F=0, V_{CC}=V_o$	-	5	50	μΑ
	High level supply current	$I_{CCH}$	$I_F=0, V_o=OPEN$	-	0.6	1.3	mA
	Low level supply current	$I_{CCL}$	I <sub>F</sub> =10mA, V <sub>o</sub> =OPEN	-	0.8	1.3	mA
	"High→Low" input threshold current	$I_{ ext{FHL}}$	$V_o \text{=} 0.8 V,  R_L \text{=} 20 k \Omega,  V_{CC} \text{=} 15 V$ Short circuit between pin $\textcircled{2}$ and pin $\textcircled{8}$	-	1.5	5	mA
	Isolation resistance	R <sub>ISO</sub>	T <sub>a</sub> =25°C, DC500V, 40 to 60%RH	5×10 <sup>10</sup>	1011	_	Ω
	Floating capacitance	$C_{\rm f}$	T <sub>a</sub> =25°C, V=0, f=1MHz	-	0.6	1	pF
cs	Internal pull-up resistance	$R_{L}$	$T_a=25^{\circ}C$	14	20	25	kΩ
risti	ဗ္ဗ "High→Low" propagation delay time	t <sub>PHL</sub>	$I_F=10mA (t_{pHL}), I_F=0 (t_{pLH}),$	30	210	400	ns
cte	"Low→High" propagation delay time	t <sub>PLH</sub>	$V_{CC}=15V, R_{L}=20k\Omega, C_{L}=100pF$	270	400	550	ns
nara	Distortion of pulse width	Δtw	$V_{THLH}=2.0V, V_{THHL}=1.5V$	_	190	450	ns
Transfer characteristics	"High → Low" propagation delay time "Low → High" propagation delay time Distortion of pulse width Propagation delay skew	$T_{PSK}$	Short circuit between pin ⑦ and pin ⑧	-	200	450	ns
	Instantaneous common mode rejection voltage (High level output)	СМн	$\begin{split} &T_a\text{=}25^{\circ}\text{C}, I_F\text{=}0, V_{\text{CC}}\text{=}15\text{V},\\ &C_L\text{=}100\text{pF}, V_{\text{CM}}\text{=}1.5\text{kV}_{\text{(P-P)}}, R_L\text{=}20\text{k}\Omega,\\ &V_O\text{>}3.0\text{V}, \text{Short circuit between}\\ &\text{pin}\ \textcircled{?}\ \text{and pin}\ \textcircled{\$} \end{split}$	15	30	-	kV/μs
	Instantaneous common mode rejection voltage (Low level output)	$\mathrm{CM}_{\mathrm{L}}$	$\begin{split} &T_a\text{=}25^\circ\text{C},I_F\text{=}10\text{mA},V_{\text{CC}}\text{=}15\text{V},\\ &C_L\text{=}100\text{pF},V_{\text{CM}}\text{=}1.5\text{kV}_{\text{(P-P)}},R_L\text{=}20\text{k}\Omega,\\ &V_O\text{<}1.0\text{V},\text{Short circuit between}\\ &\text{pin}\textcircled{\tiny{2}}\text{and pin}\textcircled{\tiny{8}} \end{split}$	-15	-30	_	kV/μs

<sup>\*6</sup> It shall connect a by-pass capacitor of  $0.01\mu F$  or more between  $V_{CC}$  (pin 8) and GND (pin 5) near the device, when it measures the transfer characteristics and the output side characteristics

<sup>\*2</sup> When ambient temperature goes above 70°C, the power dissipation goes down at approx. 0.8mW/°C,(Fig.4)
\*3 When ambient temperature goes above 70°C, the power dissipation goes down

at approx. 1.8mW/°C.(Fig.4)

<sup>\*4 40</sup> to 60%RH, AC for 1minute, f=60Hz

<sup>\*5</sup> For 10s

<sup>\*7</sup> Distortion of pulse width  $\Delta tw = |t_{PHL} - t_{PLH}|$ 



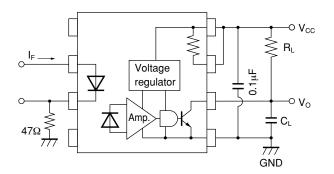
## **■** Model Line-up

Lead Form	Throug	h-Hole	SMT Gullwing		
Doolsooo	Sle	eve	Taping		
Package	50pcs/	/sleeve	1 000pcs/reel		
DIN EN60747-5-2	—— Approved			Approved	
Model No.	PC956L0NSZ0F	PC956L0YSZ0F	PC956L0NIP0F	PC956L0YIP0F	

Please contact a local SHARP sales representative to inquire about production status.



## Fig.1 Test Circuit for Propagation Delay Time



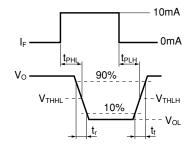
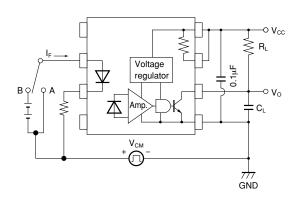


Fig.2 Test Circuit for Common Mode Rejection Voltage



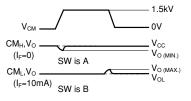


Fig.3 Forward Current vs. Ambient Temperature

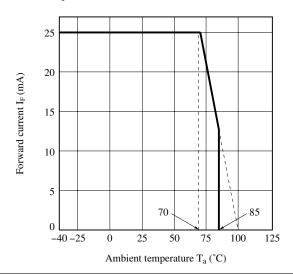


Fig.4 Power Dissipation vs. Ambient Temperature

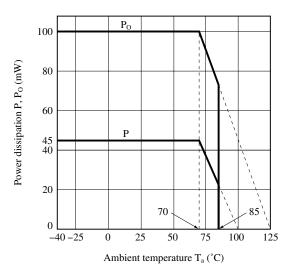




Fig.5 Output Current vs. Forward Current

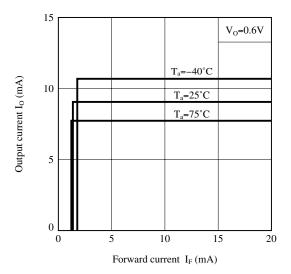


Fig.7 Relative Output Current vs. Ambient Temperature

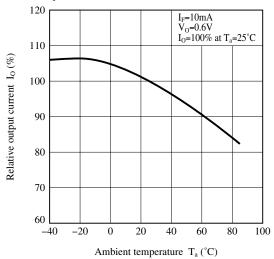


Fig.9 Low Level Output Voltage vs. Ambient Temperature

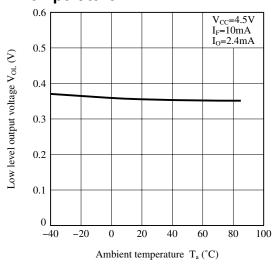


Fig.6 Forward Current vs. Forward Voltage

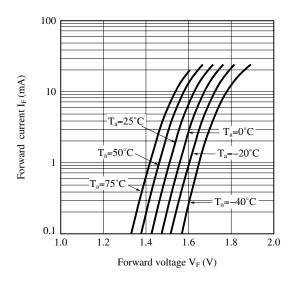


Fig.8 Input Threshold Current vs. Ambient Temperature

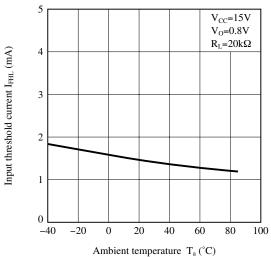


Fig.10 Supply Current vs. Ambient Temperature

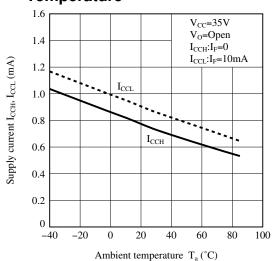




Fig.11 Propagation Delay Time vs. Ambient Temperature

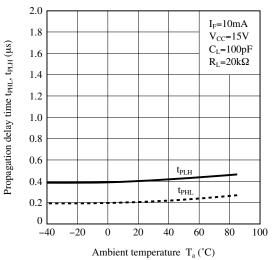


Fig.13 Propagation Delay Time vs. Load Capacitance

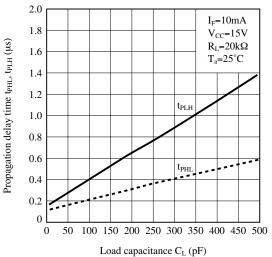


Fig.15 Propagation Delay Time vs. Forward Current

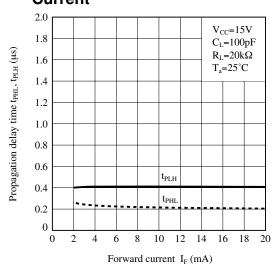


Fig.12 Propagation Delay Time vs. Load Resistance

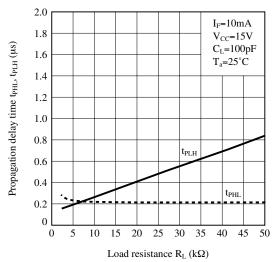
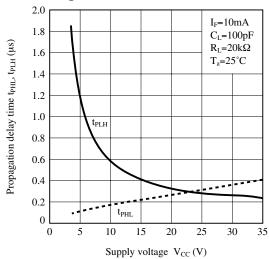


Fig.14 Propagation Delay Time vs. Supply Voltage



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



#### ■ Design Considerations

#### Recommended operating conditions

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Forward current	$I_F$	10	_	20	mA
Supply voltage	V <sub>CC</sub>	4.5	_	35	V
Output voltage	Vo	0	_	35	V
Operating temperature	Topr	-40	-	70	°C

#### Notes about static electricity

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

#### Design guide

In order to stabilize power supply line, we should certainly recommend to connect a by-pass capacitor of  $0.01\mu F$  or more between  $V_{CC}$  and GND near the device.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through LED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of LED.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

This product is not designed against irradiation and incorporates non-coherent LED.



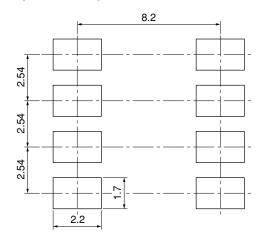
## Degradation

In general, the emission of the LED used in photocouplers will degrade over time.

In the case of long term operation, please take the general LED degradation (50% degradation over 5 years) into the design consideration.

Please decide the input current which become 2 times of MAX. I<sub>FHL</sub>.

## Recommended Foot Print (reference)



(Unit: mm)

<sup>☆</sup> For additional design assistance, please review our corresponding Optoelectronic Application Notes.



## ■ Manufacturing Guidelines

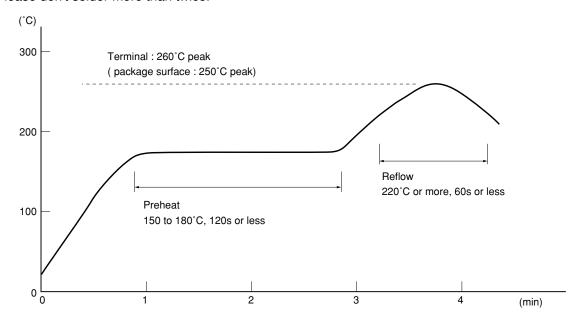
## Soldering Method

#### Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



#### Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

#### Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

#### Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



#### Cleaning instructions

#### Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

#### Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

#### Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

#### Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



## **■** Package specification

## Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

## Package method

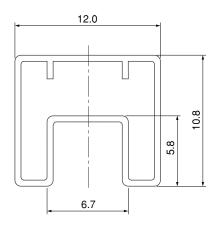
MAX. 50 pcs. of products shall be packaged in a sleeve.

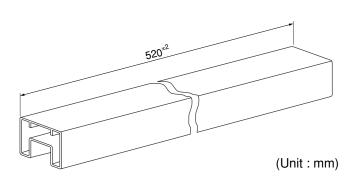
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its primary side mark on the tabless stopper side.

MAX. 20 sleeves in one case.

#### Sleeve outline dimensions







## ● Tape and Reel package

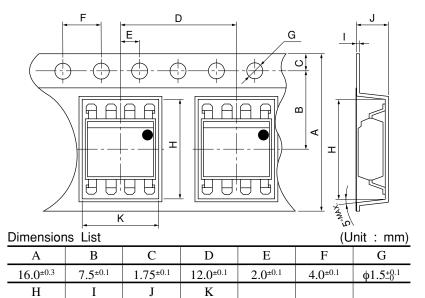
Package materials

Carrier tape: A-PET (with anti-static material)

Cover tape: PET (three layer system)

Reel: PS

Carrier tape structure and Dimensions



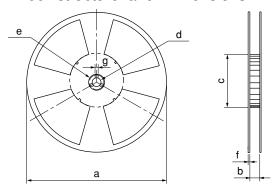
 $10.2^{\pm0.1}$ 

#### Reel structure and Dimensions

 $10.4^{\pm0.1}$ 

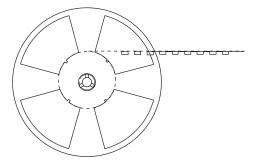
 $0.4^{\pm0.05}$ 

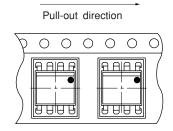
 $4.2^{\pm0.1}$ 



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
330	17.5 <sup>±1.5</sup>	100±1.0	13±0.5	
e	f	g		
23 <sup>±1.0</sup>	2.0 <sup>±0.5</sup>	2.0 <sup>±0.5</sup>		

## Direction of product insertion





[Packing: 1 000pcs/reel]



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  - --- Office automation equipment
  - --- Telecommunication equipment [terminal]
  - --- Test and measurement equipment
  - --- Industrial control
  - --- Audio visual equipment
  - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

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- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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  - --- Telecommunication equipment [trunk lines]
  - --- Nuclear power control equipment
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[E231] Sheet No.: D2-A05502EN